

Features

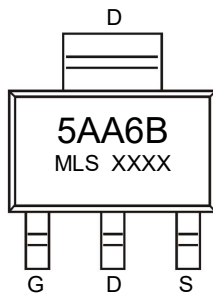
- Fast switching capability
- 100% avalanche tested
- Improved dv/dt capability

Product Summary

V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
500V	25Ω@10V	0.6A

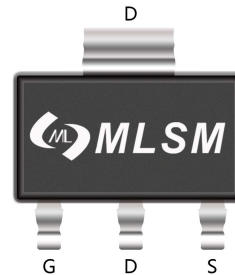
Application

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

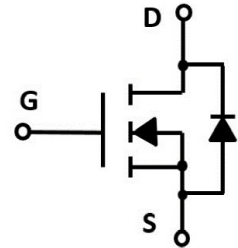


5AA6B: Device code
 XXXX: Code

Marking and pin assignment



SOT-223 top view



Schematic diagram



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V _{DS}	Drain-Source Breakdown Voltage		500	V
V _{GS}	Gate-Source Voltage		±30	V
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-50 to 155	°C
I _S	Diode Continuous Forward Current	Tc=25°C	0.6	A

Mounted on Large Heat Sink

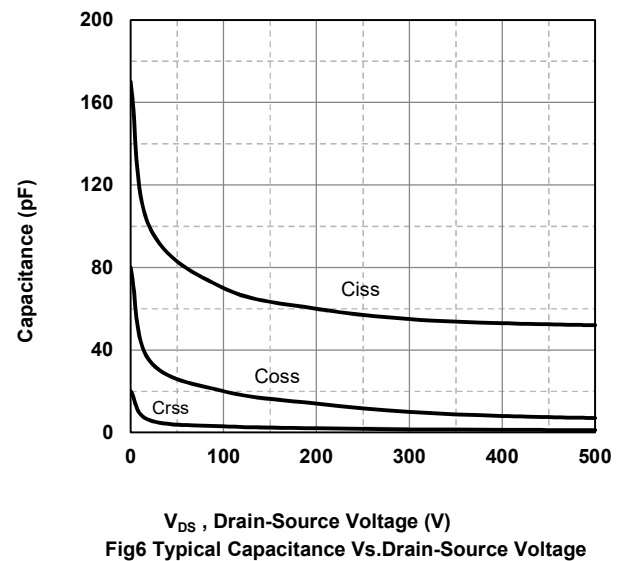
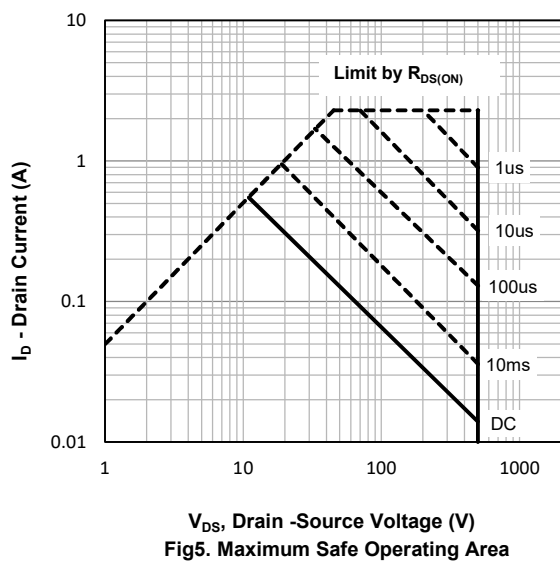
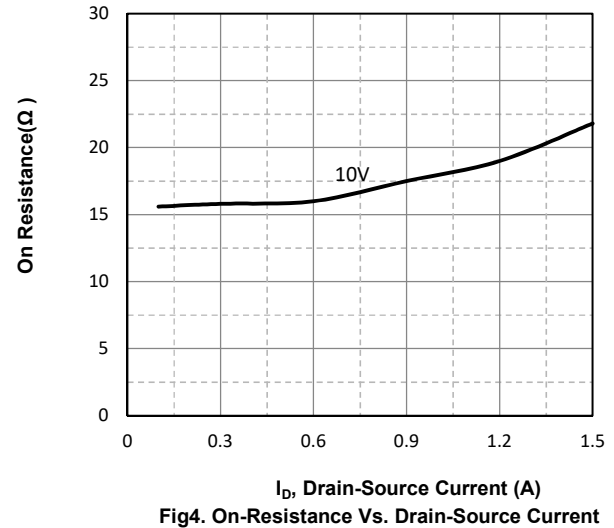
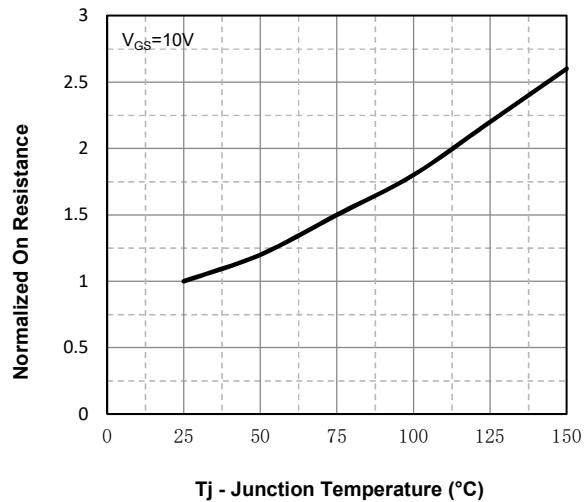
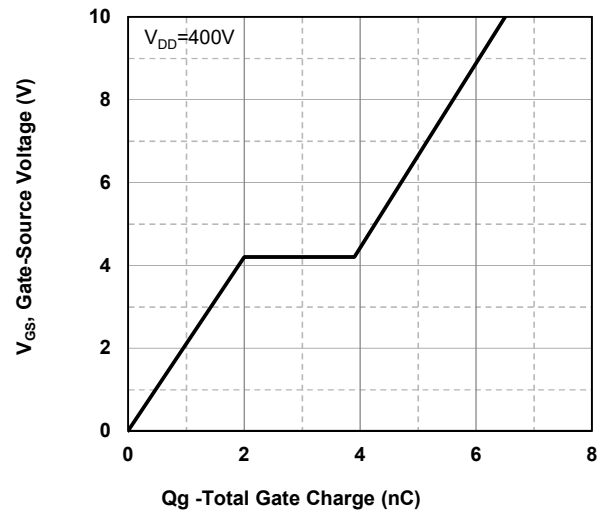
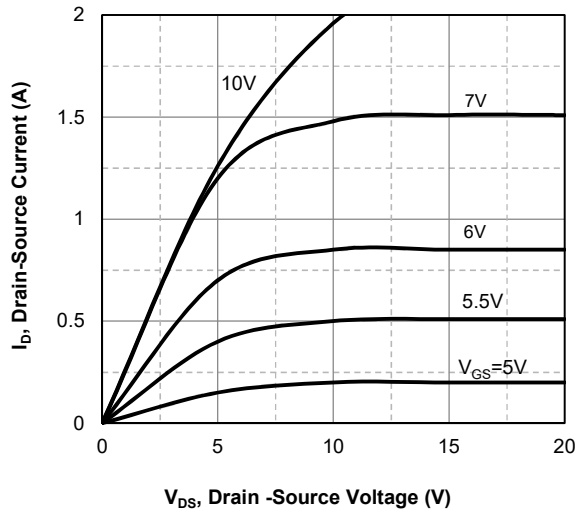
I_{DM}	Pulse Drain Current Tested	$T_c=25^{\circ}C$	2.4	A
I_D	Continuous Drain Current	$T_c=25^{\circ}C$	0.6	A
P_D	Maximum Power Dissipation	$T_c=25^{\circ}C$	0.5	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient		150	°C/W

Ordering Information (Example)

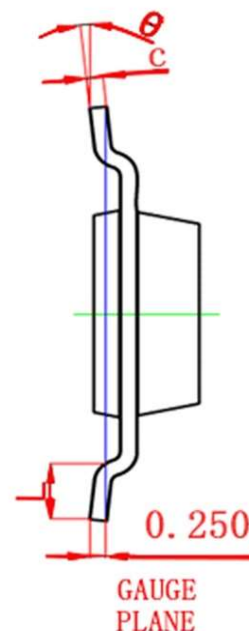
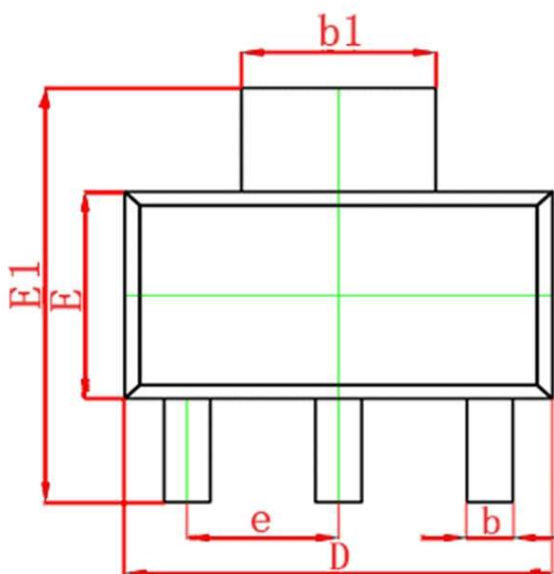
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MT5AA6B	SOT-223	5AA6B	2,500	5,000	35,000	13"reel

Electrical Characteristics (T _J =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
B _{V(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	500	–	–	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =500V, V _{GS} =0V	–	–	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±30V, V _{DS} =0V	–	–	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1	–	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =0.3A	–	16	25	Ω
Dynamic Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =25V, V _{GS} =0V, f=1MHz	–	51	–	pF
C _{OSS}	Output Capacitance		–	10	–	pF
C _{RSS}	Reverse Transfer Capacitance		–	1.2	–	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DD} =400V, I _D =0.6A, V _{GS} =10V	–	5	–	nC
Q _{gs}	Gate Source Charge		–	1.5	–	nC
Q _{gd}	Gate Drain Charge		–	1.4	–	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =250V, I _D =0.3A, V _{GS} =10V, R _G =25Ω	–	2.2	–	nS
t _r	Turn-on Rise Time		–	36	–	nS
t _{d(off)}	Turn-Off Delay Time		–	18	–	nS
t _f	Turn-Off Fall Time		–	65	–	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25°C, I _S =0.6A	–	–	1.2	V

Typical Operating Characteristics



SOT-223 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	--	1.800	--	0.071
A1	0.020	0.100	0.001	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.840	0.026	0.033
b1	2.900	3.100	0.114	0.122
c	0.230	0.350	0.009	0.014
D	6.300	6.700	0.248	0.264
E	3.300	3.700	0.130	0.146
E1	6.700	7.300	0.264	0.287
e	2.300(BSC)		0.091(BSC)	
L	0.750	--	0.030	--
θ	0°	10°	0°	10°